SCES158H-DECEMBER 1998-REVISED MARCH 2005

### **FEATURES**

- Member of the Texas Instruments Widebus™
   Family
- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- DOC<sup>™</sup> (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Dynamic Drive Capability Is Equivalent to Standard Outputs With  $I_{OH}$  and  $I_{OL}$  of  $\pm 24$  mA at 2.5-V  $V_{CC}$

- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- Package Options Include Plastic Thin Shrink Small-Outline (DGG) and Thin Very Small-Outline (DGV) Packages

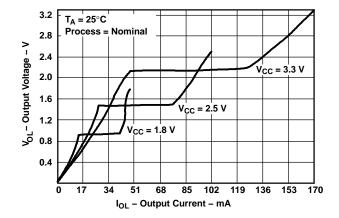
## **DESCRIPTION/ORDERING INFORMATION**

A Dynamic Output Control (DOC) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V<sub>OL</sub> vs I<sub>OL</sub> and V<sub>OH</sub> vs I<sub>OH</sub> curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC) Circuitry Technology and Applications*, literature number SCEA009.

## **ORDERING INFORMATION**

T <sub>A</sub>	PACK	AGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	TSSOP – DGG	Tape and reel	SN74AVC16374DGGR	AVC16374
-40°C to 85°C	TVSOP - DGV	Tape and reel	SN74AVC16374DGVR	CVA374
	VFBGA – GQL	Tape and reel	SN74AVC16374GQLR	CVA374

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



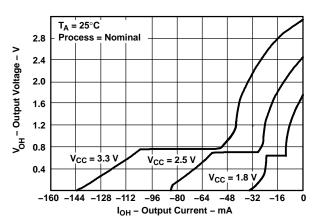


Figure 1. Output Voltage vs Output Current

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## **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

This 16-bit edge-triggered D-type flip-flop is operational at 1.2-V to 3.6-V  $V_{CC}$ , but is designed specifically for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74AVC16374 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. It can be used as two 8-bit flip-flops or one 16-bit flip-flop. On the positive transition of the clock (CLK) input, the Q outputs of the flip-flop take on the logic levels at the data (D) inputs.  $\overline{OE}$  can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect internal operations of the flip-flop. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using loff. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74AVC16374 is characterized for operation from -40°C to 85°C.

### **GQL PACKAGE** (TOP VIEW) 1 2 3 4 5 6 000000 В 000000 000000 С 000000 D $\circ$ Ε $\circ$ OOF CC000000 G 000000 Н 000000 J 000000

## TERMINAL ASSIGNMENTS(1)

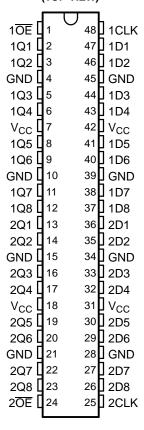
	1	2	3	4	5	6
Α	1 <del>OE</del>	NC	NC	NC	NC	1CLK
В	1Q2	1Q1	GND	GND	1D1	1D2
С	1Q4	1Q3	V <sub>CC</sub>	V <sub>CC</sub>	1D3	1D4
D	1Q6	1Q5	GND	GND	1D5	1D6
E	1Q8	1Q7			1D7	1D8
F	2Q1	2Q2			2D2	2D1
G	2Q3	2Q4	GND	GND	2D4	2D3
Н	2Q5	2Q6	V <sub>CC</sub>	V <sub>CC</sub>	2D6	2D5
J	2Q7	2Q8	GND	GND	2D8	2D7
K	2 <del>OE</del>	NC	NC	NC	NC	2CLK

(1) NC - No internal connection



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# DGG OR DGV PACKAGE (TOP VIEW)



# FUNCTION TABLE (EACH 8-BIT FLIP FLOP)

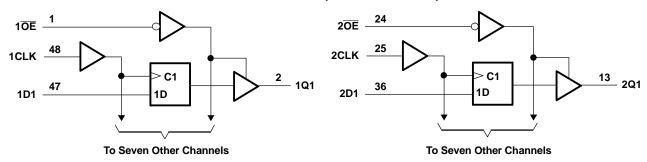
	INPUTS	OUTPUT	
ŌĒ	CLK	D	Q
L	1	Н	Н
L	$\uparrow$	L	L
L	H or L	Χ	$Q_0$
Н	X	Χ	Z



#### LOGIC SYMBOL(1) 1 10E 1EN 48 1CLK > C1 24 2OE 2EN 25 2CLK > C2 47 2 1D1 1D 1 ▽ 1Q1 3 46 1D2 1Q2 5 44 1D3 1Q3 6 43 1D4 1Q4 8 41 1D5 1Q5 40 9 1D6 1Q6 38 11 1Q7 1D7 37 12 1D8 1Q8 13 36 2D1 2 ▽ 2Q1 35 14 2D2 2Q2 33 16 2D3 2Q3 17 32 2Q4 2D4 30 19 2Q5 2D5 29 20 2D6 2Q6 27 22 2Q7 2D7 26 23 2D8 2Q8

(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## **LOGIC DIAGRAM (POSITIVE LOGIC)**





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# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

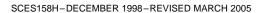
			MIN	MAX	UNIT		
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V		
VI	Input voltge range <sup>(2)</sup>		-0.5	4.6	V		
Vo	Voltage range applied to any output in the	he high-impedance or power-off state <sup>(2)</sup>	-0.5	4.6	V		
Vo	Voltage range applied to any output in the	oltage range applied to any output in the high or low state (2)(3)					
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA		
I <sub>OK</sub>	Output clamp current		-50	mA			
Io	Continuous output current			±50	mA		
	Continuous current through each V <sub>CC</sub> or	r GND		±100	mA		
		DGG package		70			
$\theta_{JA}$	Package thermal impedance (4)	Package thermal impedance (4) DGV package					
			42				
T <sub>stg</sub>	Storage temperature range	GQL package range					

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods my affect device reliability.

<sup>(2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current ratings is observed.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51.





# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V	Cupality voltage	Operating	1.4	3.6	V
$V_{CC}$	Supply voltage	Data retention only	1.2		V
		V <sub>CC</sub> = 1.2 V	V <sub>cc</sub>		
		V <sub>CC</sub> = 1.4 V to 1.6 V	$0.65 \times V_{CC}$		
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		
		V <sub>CC</sub> = 3 V to 3.6 V	2		
		V <sub>CC</sub> = 1.2 V		GND	
		V <sub>CC</sub> = 1.4 V to 1.6 V		$0.35 \times V_{CC}$	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	
		V <sub>CC</sub> = 3 V to 3.6 V		0.8	
$V_{I}$	Input voltage		0	3.6	V
V	Output valtage	Active state	0	$V_{CC}$	V
Vo	Output voltage	3-state	0	3.6	V
		V <sub>CC</sub> = 1.4 V to 1.6 V		-2	
	Static high-level output current <sup>(2)</sup>	V <sub>CC</sub> = 1.65 V to 1.95 V		-4	mA
I <sub>OHS</sub>	Static riigh-level output current	V <sub>CC</sub> = 2.3 V to 2.7 V		-8	mA
		V <sub>CC</sub> = 3 V to 3.6 V		-12	
		V <sub>CC</sub> = 1.4 V to 1.6 V		2	
	Static low-level output current <sup>(2)</sup>	V <sub>CC</sub> = 1.65 V to 1.95 V		4	mA
I <sub>OLS</sub>	Static low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		8	IIIA
		V <sub>CC</sub> = 3 V to 3.6 V		12	
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 1.4 V to 3.6 V		5	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

 <sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
 (2) Dynamic drive capability is equivalent to standard outputs with I<sub>OH</sub> and I<sub>OL</sub> of ±24 mA at 2.5-V V<sub>CC</sub>. See Figure 1 for V<sub>OL</sub> vs I<sub>OL</sub> and V<sub>OH</sub> vs I<sub>OH</sub> characteristics. Refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC™) Circuitry Technology and Applications*, literature number SCEA009.



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## **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER	TEST	CONDITIONS	V <sub>cc</sub>	MIN	TYP(1)	MAX	UNIT
		$I_{OHS} = -100 \mu A$		1.4 V to 3.6 V	$V_{CC} - 0.2$			
		$I_{OHS} = -2 \text{ mA},$	V <sub>IH</sub> = 0.91 V	1.4 V	1.05			
$V_{OH}$		$I_{OHS} = -4 \text{ mA},$	V <sub>IH</sub> = 1.07 V	1.65 V	1.2			V
		$I_{OHS} = -8 \text{ mA},$	$V_{IH} = 1.7 V$	2.3 V	1.75			
		$I_{OHS} = -12 \text{ mA},$	$V_{IH} = 2 V$	3 V	2.3			
		$I_{OLS} = 100 \mu\text{A}$		1.4 V to 3.6 V			0.2	
		$I_{OLS} = 2 \text{ mA},$	$V_{IL} = 0.49 V$	1.4 V			0.4	
$V_{OL}$		$I_{OLS} = 4 \text{ mA},$	$V_{IL} = 0.57 V$	1.65 V			0.45	V
		$I_{OLS} = 8 \text{ mA},$	$V_{IL} = 0.7 V$	2.3 V			0.55	
		$I_{OLS} = 12 \text{ mA},$	$V_{IL} = 0.8 V$	3 V			0.7	
I		$V_I = V_{CC}$ or GND		3.6 V			±2.5	μΑ
I <sub>off</sub>		$V_I$ or $V_O = 3.6 \text{ V}$		0			±10	μΑ
I <sub>OZ</sub>		$V_O = V_{CC}$ or GND		3.6 V			±10	μΑ
I <sub>CC</sub>		$V_I = V_{CC}$ or GND,	I <sub>O</sub> = 0	3.6 V			40	μΑ
	Control inputs	V – V or CND		2.5 V		3		
0	Control inputs	$V_I = V_{CC}$ or GND		3.3 V		3		~F
Ci	Data inputa	V – V or CND		2.5 V		2.5		pF
	Data inputs	$V_I = V_{CC}$ or GND		3.3 V		2.5		
C	Outouto	V - V or CND		2.5 V		6.5		n.E
C <sub>o</sub>	Outputs	$V_O = V_{CC}$ or GND		3.3 V		6.5		pF

<sup>(1)</sup> Typical values are measured at  $V_{CC}$  = 2.5 V and 3.3 V,  $T_A$  = 25°C.

## **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted)

		V <sub>CC</sub> =	V <sub>CC</sub> = 1.2 V		V <sub>CC</sub> = 1.5 V ± 0.1 V		V <sub>CC</sub> = 1.8 V ± 0.15 V		2.5 V 2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency						160		200		200	MHz
t <sub>w</sub>	Pulse duration, CLK high or low					3.1		2.5		2.5		ns
t <sub>su</sub>	Setup time, data before CLK↑	4.1		2.7		1.9		1.4		1.4		ns
t <sub>h</sub>	Hold time, data after CLK↑	1.7		1.3		1.2		1.1		1.1		ns

## **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2 through Figure 5)

PARAMETER FROM		TO (OUTPUT)	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = ± 0.	1.5 V 1 V	V <sub>CC</sub> = ± 0.7		V <sub>CC</sub> = ± 0.		V <sub>CC</sub> = ± 0.		UNIT
	(INPUT)	(OUTPUT)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>						160		200		200		MHz
t <sub>pd</sub>	CLK	Q	7.3	1.5	8.4	1.2	6.7	0.8	4.1	0.7	3.3	ns
t <sub>en</sub>	ŌĒ	Q	7.4	1.6	8.5	1.6	6.7	0.9	4.3	0.7	3.4	ns
t <sub>dis</sub>	ŌĒ	Q	8.4	2.5	9.4	2.3	7.8	1	4.2	1.5	3.9	ns





# **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER			CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
_	Power dissipation capacitance Outputs enabled Outputs disabled		0	f = 10 MHz	74	81	89	pF
$C_{pd}$			$C_L = 0$ ,	1 = 10 WITZ	52	57	63	μΓ



PARAMETER MEASUREMENT INFORMATION  $V_{CC}$  = 1.2 V AND 1.5 V  $\pm$  0.1 V

WITH 3-STATE OUTPUTS

# ○ Open **2 k**Ω From Output O GND **Under Test** $C_L = 15 pF$ $2 k\Omega$ (see Note A) **LOAD CIRCUIT**

TRUMENTS

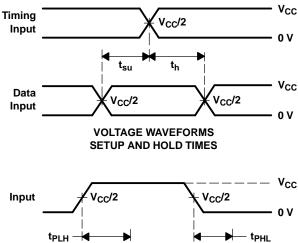
www.ti.com

#### **TEST** S1 Open t<sub>pd</sub> $\mathbf{2} \times \mathbf{V_{CC}}$ t<sub>PLZ</sub>/t<sub>PZL</sub> **GND** t<sub>PHZ</sub>/t<sub>PZH</sub>

 $V_{CC}$ 

٥v

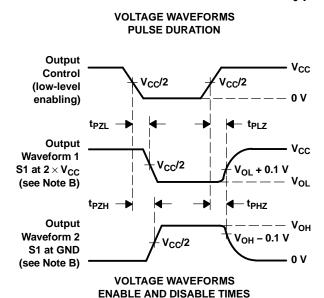
V<sub>CC</sub>/2



V<sub>CC</sub>/2

**VOLTAGE WAVEFORMS** 

**PROPAGATION DELAY TIMES** 



V<sub>CC</sub>/2

Input

NOTES: A.  $C_L$  includes probe and jig capacitance.

Output

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_r \leq$  2 ns,  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 2. Load Circuit and Voltage Waveforms

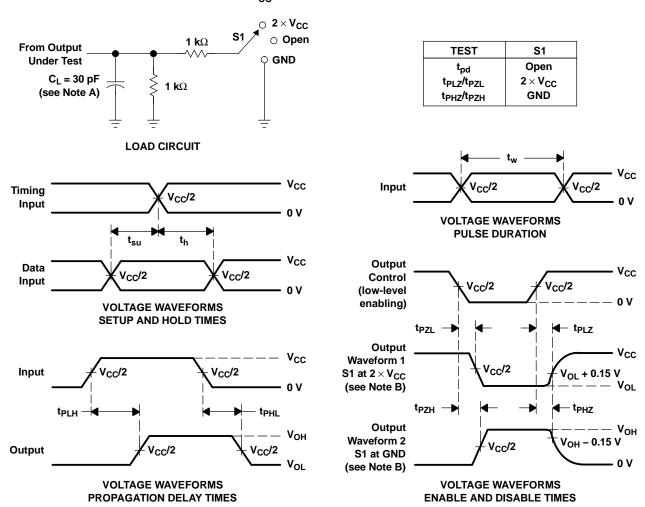
VoH

 $v_{\text{ol}}$ 

V<sub>CC</sub>/2



# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 1.8 V $\pm$ 0.15 V



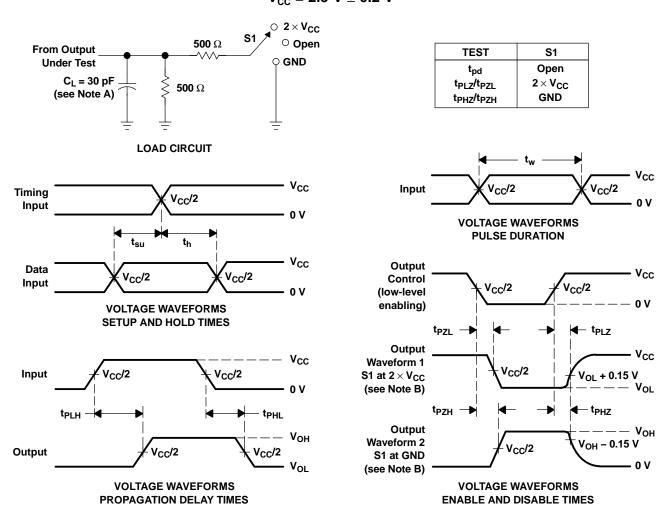
- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2$  ns,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 3. Load Circuit and Voltage Waveforms





# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.5 V $\pm$ 0.2 V

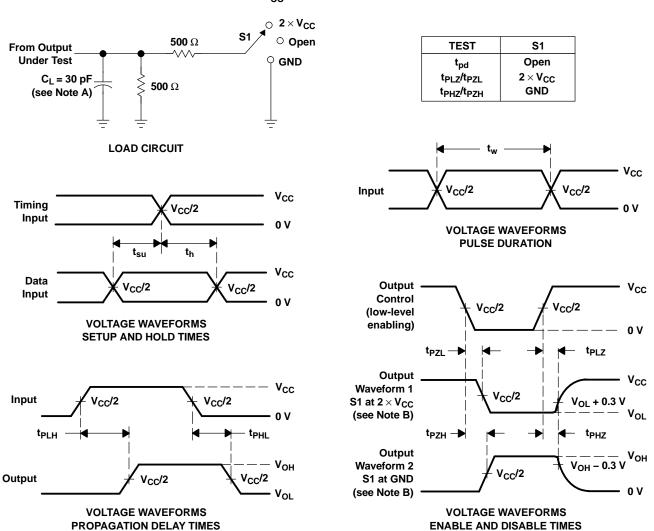


- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics:  $PRR \le 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \le 2 \text{ ns}$ ,  $t_f \le 2 \text{ ns}$ .
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 4. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{cc} = 3.3 \text{ V} \pm 0.3 \text{ V}$



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_r \leq$  2 ns,  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 5. Load Circuit and Voltage Waveforms





24-Apr-2015

### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
74AVC16374DGGRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AVC16374	Samples
SN74AVC16374DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AVC16374	Samples
SN74AVC16374DGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CVA374	Samples
SN74AVC16374GQLR	OBSOLETE	BGA MICROSTAR JUNIOR	GQL	56		TBD	Call TI	Call TI	-40 to 85		
SN74AVC16374ZQLR	ACTIVE	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CVA374	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



## PACKAGE OPTION ADDENDUM

24-Apr-2015

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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## PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC16374DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74AVC16374DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74AVC16374ZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC16374DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74AVC16374DGVR	TVSOP	DGV	48	2000	367.0	367.0	38.0
SN74AVC16374ZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	333.2	345.9	28.6

# ZQL (R-PBGA-N56)

## PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is Pb-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).

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# GQL (R-PBGA-N56)

# PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



## DGG (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

## **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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